MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data speet



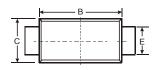
Features

- For surface mounted applications
- Low profile package
- Low incremental surge resistance, excellent clamping capability
- 200W peak pulse power capability with a10/1000 μs wave from,repetition rate (dutycycle):0.01%
- High temperature soldering guaranteed:
 260 ℃/10 seconds, at terminals



Mechanical Data

- Case: JEDEC SOD-123FL, molded plastic over passivated chip
- Polarity: Color band denotes positive end (cathode) except for bidirectional
- Mounting position: Any
- Weight: 0.006 ounces, 0.02 gram



SOD-123FL

Maximum Ratings T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Maximum P _{PK} Dissipation (PW - 10/1000 μs)	P _{PK}	200	W
Maximum P _{PK} Dissipation @ Ta = 25 °C (PW - 8/10 μs) (Note 2)	P _{PK}	1000	W
DC Power Dissipation @ Ta = 25 °C (Note 3)	P _D	385	mW
Derate above 25 °C		4.0	mW/ °C
Thermal Resistance, Junction to Ambient (Note 3)	R _{eJA}	325	°C/W
Thermal Resistance, Junction to Lead (Note 3)	R _{OJL}	26	°C/W
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

- (1) Non-repetitive current pulse at Ta = 25°C, per waveform of Fig. 2.
- (2) Non-repetitive current pulse at Ta = 25°C, per waveform of Fig. 5.
- (3) Mounted with recommended minimum pad size, DC board FR4.

TYPE	Marking	Reverse Stand-Off Voltage	Breakdown Voltage Min. @I _T	Breakdown Voltage Max. @ I _T	Test Current	Reverse Leakage @V _{RWM}	Maximum Clamping Voltage @Ipp	Peak Pulse Current
		$V_{RWM}(V)$	$V_{BR MIN}(V)$	$V_{BR\ MAX}(V)$	_T (mA)	I _R (uA)	V _C (V)	I _{PP} (mA)
PDCV300JB-MS	JK	30	33.3	36.8	1.0	1.0	48.4	4.1





FIG.1 - PULSE DERATING CURVE

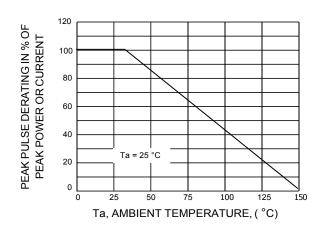


FIG.3 - STEADY STATE POWER DERATING

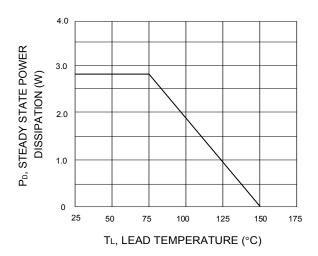


FIG.5 - 8 x 20 μ s PULSE WAVEFORM

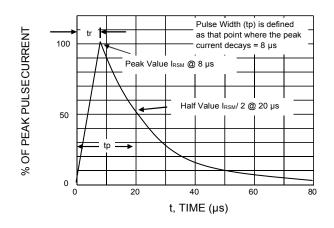


FIG.2 - 10 x 1000 µs PULSEWAVEFORM

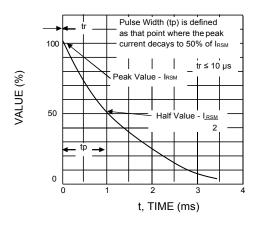


FIG.4 - PULSE RATING CURVE

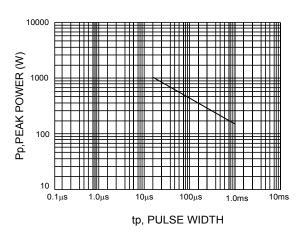
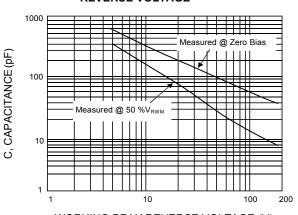
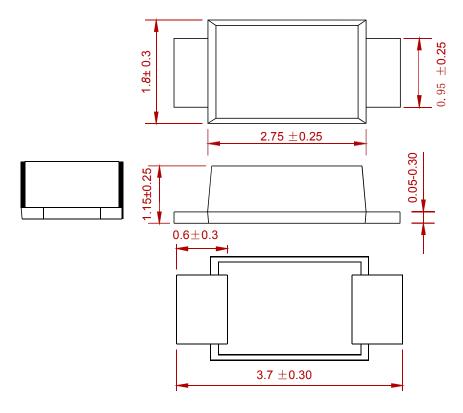


FIG. 6 - CAPACITANCE VS. WORKING PEAK REVERSE VOLTAGE

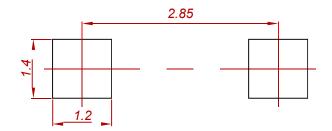


PACKAGE MECHANICAL DATA



Dimensions in millimeters

Suggested Pad Layout



Note:

- 1. Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
PDCV300JB	SOD-123FL	3000



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